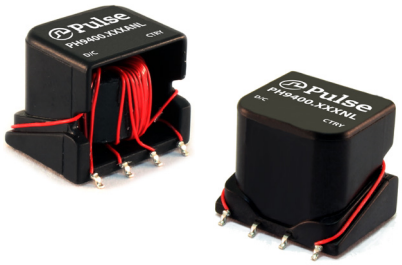
High Isolation Gate Drive Transformers

PH9400.XXXNL and PH9400.XXXANL - SMT



- *Basic and Reinforced Insulation*
- *Patent Pending Sidecar package with 12mm creepage*
- *Up to 5000Vrms gate to drive isolation*
- *600Vrms continuous isolation between windings*

Electrical Specifications @ 25°C – Operating Temperature -40°C to +125°C										
Part Number	**Turns Ratio**	**ET** (V * µsec MAX)	**Core Loss Factor K1**	**Primary Inductance** (1-4) (mH +/-35%)	**Leakage Inductance Drive to Gate** (µH MAX)	**Parasitic Capacitance Drive to Gate** (pF MAX)	**DCR Drive** (1-4) (Ω MAX)	**DCR Gates** (5-6) (7-8) (Ω MAX)	**Hi-Pot**	
									Drive-Gate (Vrms)	**Gate-Gate** (Vrms)
PH9400.XXXNL – Basic Insulation										
PH9400.111NL	1:1:1	315	0.67	4.5	5.0	60	1.8	2.5	4000	1500
PH9400.566NL	5:6:6	315	0.67	4.5	3.5	60	1.8	3.0	4000	1500
PH9400.122NL	1:2:2	250	0.84	2.88	3.5	60	1.5	4.2	4000	1500
PH9400.655NL	6:5:5	375	0.56	6.48	5.3	60	2.2	2.5	4000	1500
PH9400.211NL	2:1:1	375	0.56	6.48	8.0	60	2.2	1.6	4000	1500
PH9400.XXXANL – Reinforced Insulation										
PH9400.111ANL	1:1:1	160	1.32	1.21	2.5	45	0.9	0.9	5000	2000
PH9400.566ANL	5:6:6	155	1.36	1.12	3.0	45	0.9	1.0	5000	2000
PH9400.233ANL	2:3:3	125	1.68	0.72	2.0	45	0.7	1.0	5000	2000
PH9400.655ANL	6:5:5	185	1.14	1.62	3.0	45	1.0	0.9	5000	2000
PH9400.211ANL	2:1:1	185	1.14	1.62	3.5	45	1.0	0.55	5000	2000

Notes:

1. The max ET is calculated to limit the core loss and temperature rise at 100KHz based on a bipolar flux swing of 2100Ga Peak. This value needs to be derated for higher frequencies using the temperature rise calculation.
2. The temperature rise of the component is calculated based on the total core loss and copper loss:
   - A. To calculate total copper loss (W), use the following formula:
     Copper Loss (W) = $Irms^2$* (DCR_Drive + (# of Gates) * DCR_Gates)
   - B. To calculate total core loss (W), use the following formula:
     Copper Loss (W) = $5.1E\text{-}10 * (\text{Frequency in kHz})^{1.42} * (K1 * ET)^{2.5}$
     Where ET = (V * Duty Cycle) / Frequency
   - C. To calculate temperature rise, use the following formula:
     Temperature Rise (C) = 71 * (Core Loss(W) + Copper Loss (W))
3. Continuous isolation voltage confirmed by 125°C/1000hrs accelerated aging with the bias voltage applied between gate and drive windings.
4. ANL versions, which use triple insulated wire on both the drive and gate windings, are compliant with IEC 60950, IEC 61558, IEC 61010 & IEC 60601 for reinforced insulation. NL versions, which use triple insulated wire on just the drive winding, comply with basic insulation requirements.
5. 12mm package creepage distance satisfies IEC60950-1 & IEC61558-1/-2-16 reinforced insulation requirements for working voltage to 600Vrms max, OVC II, Pollution Degree 2 and altitude up to 2000m.
6. Unless otherwise specified, all testing is made at 100kHz, $0.1V_{AC}$.
7. Optional Tape & Reel packaging can be ordered by adding a "**T**" suffix to the part number (i.e. PH9400.111NL becomes PH9400.111NL**T**). Pulse complies to industry standard tape and reel specification EIA481.

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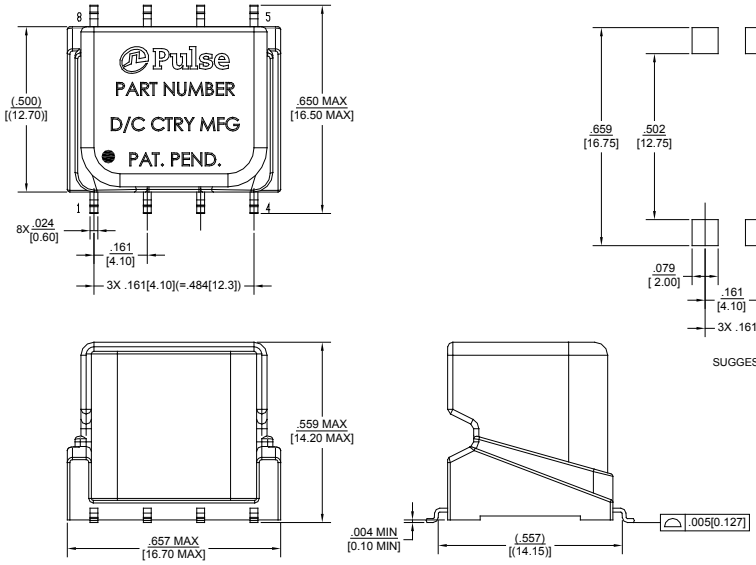
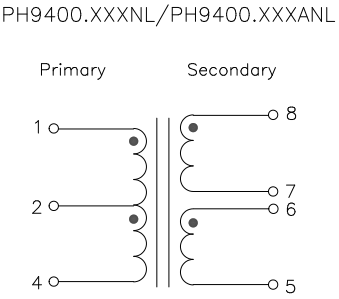
Mechanicals

PH9400.XXXNL and PH9400.XXXANL



Schematics



Weight .....2.5 grams
Tape & Reel 150/Reel
Tray 80/tray

Dimension: Inches / mm

Unless otherwise specified, all tolerances are ± .010 / 0,25

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